LM2902,LM324/LM324A,LM224/ LM224A

Quad Operational Amplifier

Features

- Internally Frequency Compensated for Unity Gain
- Large DC Voltage Gain: 100dB
- Wide Power Supply Range:
  LM224/LM224A, LM324/LM324A : 3V~32V (or ±1.5 ~ 16V)
  LM2902: 3V~26V (or ±1.5V ~ 13V)
- Input Common Mode Voltage Range Includes Ground
- Large Output Voltage Swing: 0V to V_{CC} -1.5V
- Power Drain Suitable for Battery Operation

Description

The LM324/LM324A,LM2902,LM224/LM224A consist of four independent, high gain, internally frequency compensated operational amplifiers which were designed specifically to operate from a single power supply over a wide voltage range. operation from split power supplies is also possible so long as the difference between the two supplies is 3 volts to 32 volts. Application areas include transducer amplifier, DC gain blocks and all the conventional OP Amp circuits which now can be easily implemented in single power supply systems.

14-DIP

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14-SOP

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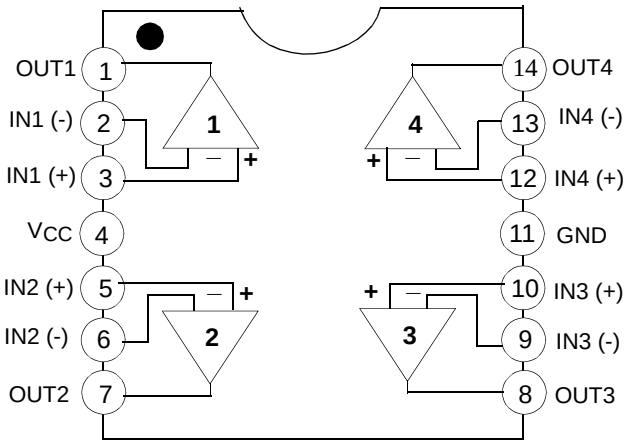
Internal Block Diagram



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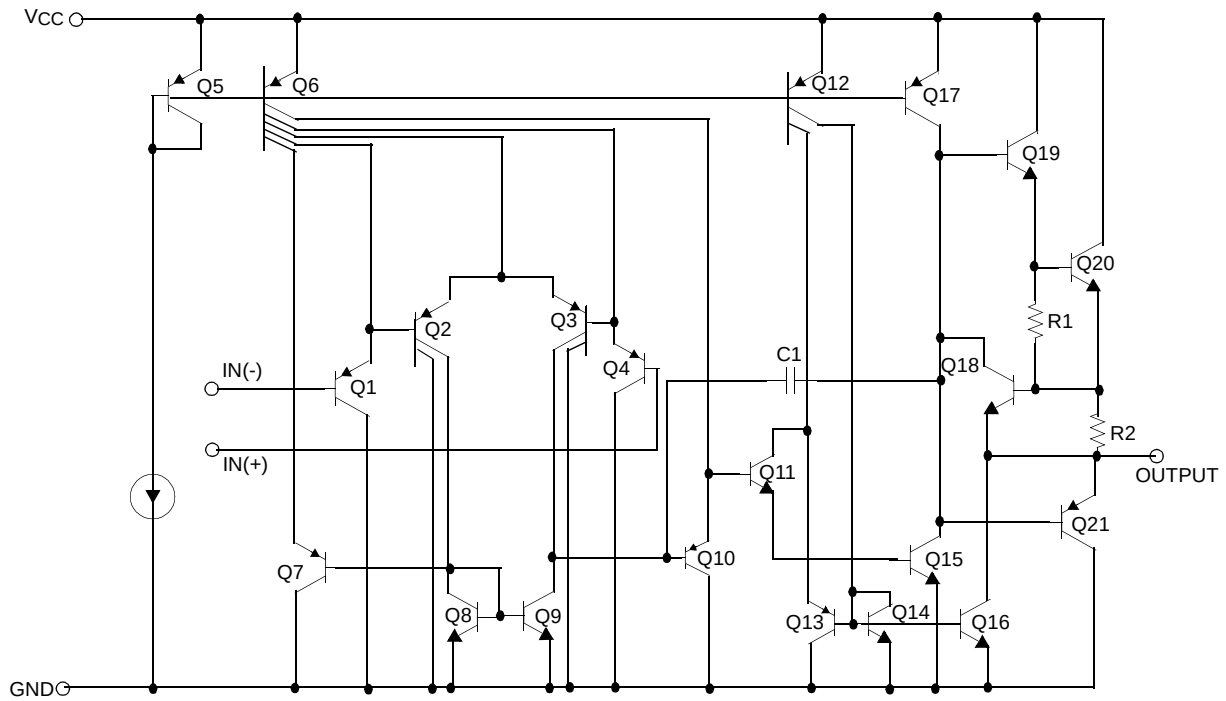
Schematic Diagram

(One Section Only)



Absolute Maximum Ratings

Parameter	Symbol	LM224/LM224A	LM324/LM324A	LM2902	Unit
Power Supply Voltage	V_{CC}	±16 or 32	±16 or 32	±13 or 26	V
Differential Input Voltage	$V_{I(DIFF)}$	32	32	26	V
Input Voltage	V_I	-0.3 to +32	-0.3 to +32	-0.3 to +26	V
Output Short Circuit to GND Vcc≤15V, T_A=25°C(one Amp)	-	Continuous	Continuous	Continuous	-
Power Dissipation, T_A=25°C 14-DIP 14-SOP	P_D	1310 640	1310 640	1310 640	mW
Operating Temperature Range	T_{OPR}	-25 ~ +85	0 ~ +70	-40 ~ +85	°C
Storage Temperature Range	T_{STG}	-65 ~ +150	-65 ~ +150	-65 ~ +150	°C

Thermal Data

Parameter	Symbol	Value	Unit
Thermal Resistance Junction-Ambient Max. 14-DIP 14-SOP	Rθja	95 195	°C/W

Electrical Characteristics

(V_{CC} = 5.0V, V_{EE} = GND, T_A = 25°C, unless otherwise specified)

Parameter	Symbol	Conditions	LM224			LM324			LM2902			Unit
			Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
Input Offset Voltage	V_{IO}	V_{CM} = 0V to V_{CC} -1.5V $V_{O(P)}$ = 1.4V, R_S = 0Ω (Note1)	-	1.5	5.0	-	1.5	7.0	-	1.5	7.0	mV
Input Offset Current	I_{IO}	V_{CM} = 0V	-	2.0	30	-	3.0	50	-	3.0	50	nA
Input Bias Current	I_{BIAS}	V_{CM} = 0V	-	40	150	-	40	250	-	40	250	nA
Input Common-Mode Voltage Range	$V_{I(R)}$	Note1	0	-	V_{CC} -1.5	0	V_{CC} -1.5	-	0	-	V_{CC} -1.5	V
Supply Current	I_{CC}	R_L = ∞,V_{CC} = 30V (LM2902,V_{CC}=26V)	-	1.0	3	-	1.0	3	-	1.0	3	mA
		R_L = ∞,V_{CC} = 5V	-	0.7	1.2	-	0.7	1.2	-	0.7	1.2	mA
Large Signal Voltage Gain	G_V	V_{CC} = 15V,R_L=2kΩ $V_{O(P)}$ = 1V to 11V	50	100	-	25	100	-	25	100	-	V/mV
Output Voltage Swing	$V_{O(H)}$	Note1, R_L = 2kΩ	26	-	-	26	-	-	22	-	-	V
		Note1, R_L=10kΩ	27	28	-	27	28	-	23	24	-	V
	$V_{O(L)}$	V_{CC} = 5V,R_L=10kΩ	-	5	20	-	5	20	-	5	100	mV
Common-Mode Rejection Ratio	CMRR	-	70	85	-	65	75	-	50	75	-	dB
Power Supply Rejection Ratio	PSRR	-	65	100	-	65	100	-	50	100	-	dB
Channel Separation	CS	f = 1kHz to 20kHz (Note2)	-	120	-	-	120	-	-	120	-	dB
Short Circuit to GND	I_{SC}	V_{CC} = 15V	-	40	60	-	40	60	-	40	60	mA
Output Current	I_{SOURCE}	$V_{I(+)}$ = 1V, $V_{I(-)}$ = 0V V_{CC} = 15V $V_{O(P)}$ = 2V	20	40	-	20	40	-	20	40	-	mA
	I_{SINK}	$V_{I(+)}$ = 0V, $V_{I(-)}$ = 1V V_{CC} = 15V $V_{O(P)}$ = 2V	10	13	-	10	13	-	10	13	-	mA
		$V_{I(+)}$ = 0V, $V_{I(-)}$ = 1V V_{CC} = 5V,$V_{O(R)}$ = 200mV	12	45	-	12	45	-	-	-	-	μA
Differential Input Voltage	$V_{I(DIFF)}$	-	-	-	V_{CC}	-	-	V_{CC}	-	-	V_{CC}	V

Note :

1. V_{CC}=30V for LM224 and LM324 , V_{CC} = 26V for LM2902
2. This parameter, although guaranteed, is not 100% tested in production.

Electrical Characteristics (Continued)

(V_{CC} = 5.0V, V_{EE} = GND, unless otherwise specified)
The following specification apply over the range of -25°C ≤ T_A ≤ + 85°C for the LM224; and the 0°C ≤ T_A ≤ +70°C for the LM324 ; and the -40°C ≤ T_A ≤ +85°C for the LM2902

Parameter	Symbol	Conditions	LM224			LM324			LM2902			Unit
			Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
Input Offset Voltage	V_{IO}	V_{ICM} = 0V to V_{CC} -1.5V $V_{O(P)}$ = 1.4V, R_S = 0Ω (Note1)	-	-	7.0	-	-	9.0	-	-	10.0	mV
Input Offset Voltage Drift	$\Delta V_{IO}/\Delta T$	R_S = 0Ω (Note2)	-	7.0	-	-	7.0	-	-	7.0	-	µV/°C
Input Offset Current	I_{IO}	V_{CM} = 0V	-	-	100	-	-	150	-	-	200	nA
Input Offset Current Drift	$\Delta I_{IO}/\Delta T$	R_S = 0Ω (Note2)	-	10	-	-	10	-	-	10	-	pA/°C
Input Bias Current	I_{BIAS}	V_{CM} = 0V	-	-	300	-	-	500	-	-	500	nA
Input Common-Mode Voltage Range	$V_{I(R)}$	Note1	0	-	V_{CC} -2.0	0	-	V_{CC} -2.0	0	-	V_{CC} -2.0	V
Large Signal Voltage Gain	G_V	V_{CC} = 15V, R_L = 2.0kΩ $V_{O(P)}$ = 1V to 11V	25	-	-	15	-	-	15	-	-	V/mV
Output Voltage Swing	$V_{O(H)}$	Note1, R_L=2kΩ	26	-	-	26	-	-	22	-	-	V
		Note1, R_L=10kΩ	27	28	-	27	28	-	23	24	-	V
	$V_{O(L)}$	V_{CC} = 5V, R_L=10kΩ	-	5	20	-	5	20	-	5	100	mV
Output Current	I_{SOURCE}	$V_{I(+)}$ = 1V, $V_{I(-)}$ = 0V V_{CC} = 15V, VO(P) = 2V	10	20	-	10	20	-	10	20	-	mA
	I_{SINK}	$V_{I(+)}$ = 0V, $V_{I(-)}$ = 1V V_{CC} = 15V, $V_{O(P)}$ = 2V	10	13	-	5	8	-	5	8	-	mA
Differential Input Voltage	$V_{I(DIFF)}$	-	-	-	V_{CC}	-	-	V_{CC}	-	-	V_{CC}	V

Note:
1. V_{CC}=30V for LM224 and LM324 , V_{CC} = 26V for LM2902
2. These parameters, although guaranteed, are not 100% tested in production.

Electrical Characteristics (Continued)

(V_{CC} = 5.0V, V_{EE} = GND, T_A = 25°C, unless otherwise specified)

Parameter	Symbol	Conditions		LM224A			LM324A			Unit
				Min.	Typ.	Max.	Min.	Typ.	Max.	
Input Offset Voltage	V_{IO}	V_{CM} = 0V to V_{CC} -1.5V $V_{O(P)}$ = 1.4V, R_S = 0Ω (Note1)		-	1.0	3.0	-	1.5	3.0	mV
Input Offset Current	I_{IO}	V_{CM} = 0V		-	2	15	-	3.0	30	nA
Input Bias Current	I_{BIAS}	V_{CM} = 0V		-	40	80	-	40	100	nA
Input Common-Mode Voltage Range	$V_{I(R)}$	V_{CC} = 30V		0	-	V_{CC} -1.5	0	-	V_{CC} -1.5	V
Supply Current	I_{CC}	V_{CC} = 30V, R_L = ∞		-	1.5	3	-	1.5	3	mA
		V_{CC} = 5V, R_L = ∞		-	0.7	1.2	-	0.7	1.2	mA
Large Signal Voltage Gain	G_V	V_{CC} = 15V, R_L= 2kΩ $V_{O(P)}$ = 1V to 11V		50	100	-	25	100	-	V/mV
Output Voltage Swing	$V_{O(H)}$	Note1	R_L = 2kΩ	26	-	-	26	-	-	V
			R_L = 10kΩ	27	28	-	27	28	-	V
	$V_{O(L)}$	V_{CC} = 5V, R_L=10kΩ		-	5	20	-	5	20	mV
Common-Mode Rejection Ratio	CMRR	-		70	85	-	65	85	-	dB
Power Supply Rejection Ratio	PSRR	-		65	100	-	65	100	-	dB
Channel Separation	CS	f = 1kHz to 20kHz (Note2)		-	120	-	-	120	-	dB
Short Circuit to GND	I_{SC}	V_{CC} = 15V		-	40	60	-	40	60	mA
Output Current	I_{SOURCE}	$V_{I(+)}$ = 1V, $V_{I(-)}$ = 0V V_{CC} =15V, $V_{O(P)}$ = 2V		20	40	-	20	40	-	mA
	I_{SINK}	$V_{I(+)}$ = 0V, $V_{I(-)}$ = 1V V_{CC} = 15V, $V_{O(P)}$ = 2V		10	20	-	10	20	-	mA
		$V_{I(+)}$ = 0v, $V_{I(-)}$ = 1V V_{CC} = 5V $V_{O(P)}$ = 200mV		12	50	-	12	50	-	μA
Differential Input Voltage	$V_{I(DIFF)}$	-		-	-	V_{CC}	-	-	V_{CC}	V

Note:

1. V_{CC}=30V for LM224A, LM324A
2. This parameter, although guaranteed, is not 100% tested in production.

Electrical Characteristics (Continued)

(V_{CC} = 5.0V, V_{EE} = GND, unless otherwise specified)
The following specification apply over the range of -25°C ≤ T_A ≤ +85°C for the LM224A; and the 0°C ≤ T_A ≤ +70°C for the LM324A

Parameter	Symbol	Conditions		LM224A			LM324A			Unit
				Min.	Typ.	Max.	Min.	Typ.	Max.	
Input Offset Voltage	V_{IO}	V_{CM} = 0V to V_{CC} -1.5V $V_{O(P)}$ = 1.4V, R_S = 0Ω (Note1)		-	-	4.0	-	-	5.0	mV
Input Offset Voltage Drift	$\Delta V_{IO}/\Delta T$	R_S = 0Ω (Note2)		-	7.0	20	-	7.0	30	μV/°C
Input Offset Current	I_{IO}	V_{CM} = 0V		-	-	30	-	-	75	nA
Input Offset Current Drift	$\Delta I_{IO}/\Delta T$	R_S = 0Ω (Note2)		-	10	200	-	10	300	pA/°C
Input Bias Current	I_{BIAS}	-		-	40	100	-	40	200	nA
Input Common-Mode Voltage Range	$V_{I(R)}$	Note1		0	-	V_{CC} -2.0	0	-	V_{CC} -2.0	V
Large Signal Voltage Gain	G_V	V_{CC} = 15V, R_L= 2.0kΩ		25	-	-	15	-	-	V/mV
Output Voltage Swing	$V_{O(H)}$	Note1	R_L = 2kΩ	26	-	-	26	-	-	V
			R_L = 10kΩ	27	28	-	27	28	-	V
	$V_{O(L)}$	V_{CC} = 5V, R_L= 10kΩ		-	5	20	-	5	20	mV
Output Current	I_{SOURCE}	$V_{I(+)}$ = 1V, $V_{I(-)}$ = 0V V_{CC} = 15V, $V_{O(P)}$ = 2V		10	20	-	10	20	-	mA
	I_{SINK}	$V_{I(+)}$ = 0V, $V_{I(-)}$ = 1V V_{CC} = 15V, $V_{O(P)}$ = 2V		5	8	-	5	8	-	mA
Differential Input Voltage	$V_{I(DIFF)}$	-		-	-	V_{CC}	-	-	V_{CC}	V

Note:
1. V_{CC}=30V for LM224A and LM324A.
2. These parameters, although guaranteed, are not 100% tested in production.

Typical Performance Characteristics

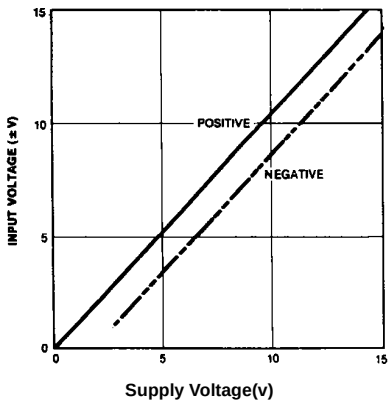


Figure 1. Input Voltage Range vs Supply Voltage

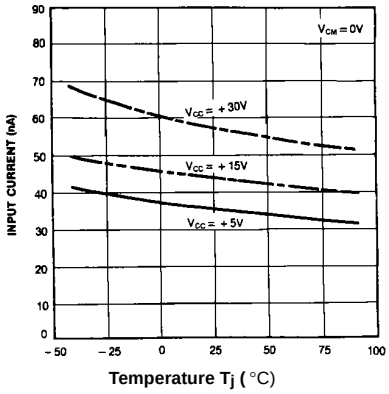


Figure 2. Input Current vs Temperature

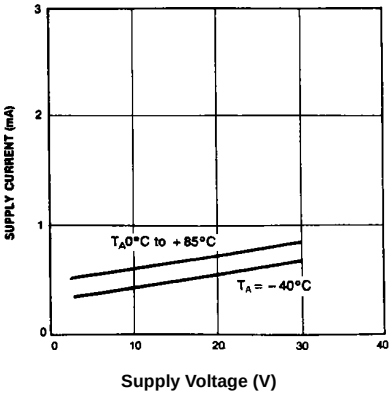


Figure 3. Supply Current vs Supply Voltage

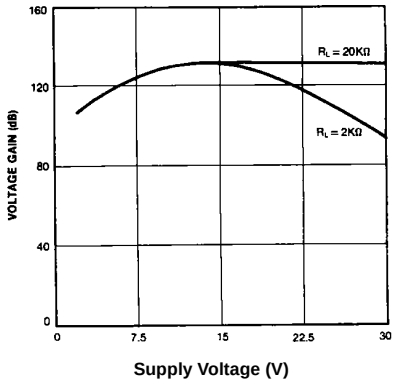


Figure 4. Voltage Gain vs Supply Voltage

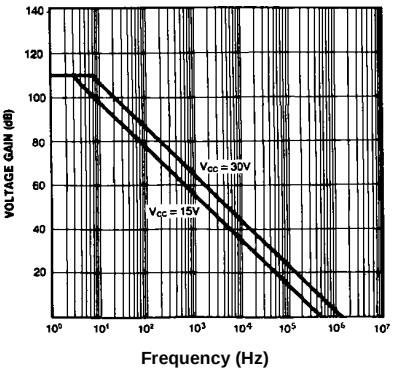


Figure 5. Open Loop Frequency Response

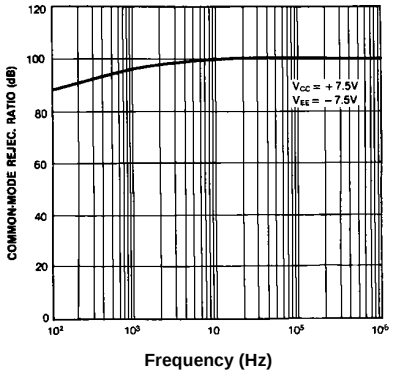


Figure 6. Common mode Rejection Ratio

Typical Performance Characteristics (Continued)

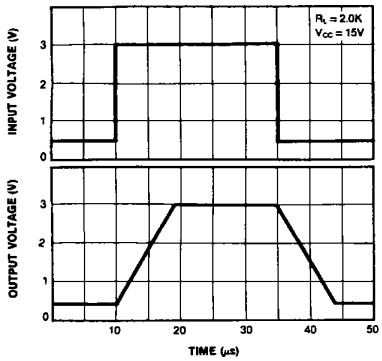


Figure 7. Voltage Follower Pulse Response

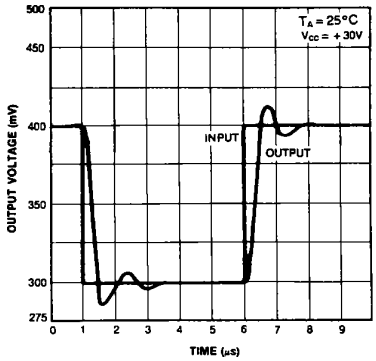


Figure 8. Voltage Follower Pulse Response (Small Signal)

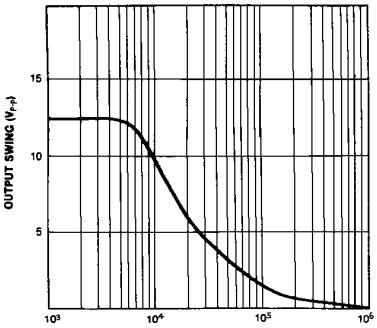


Figure 8. Large Signal Frequency Response

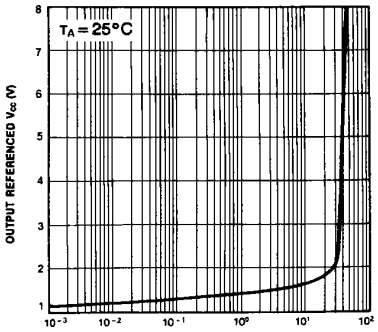


Figure 9. Output Characteristics vs Current Sourcing

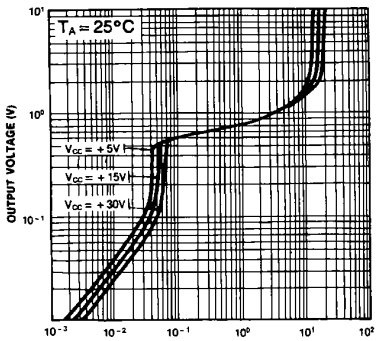


Figure 10. Output Characteristics vs Current Sinking

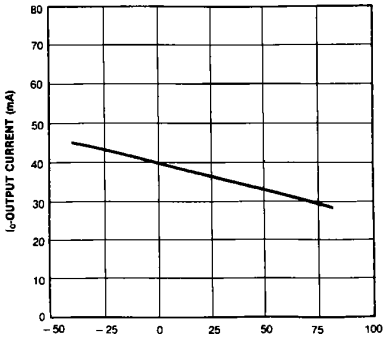


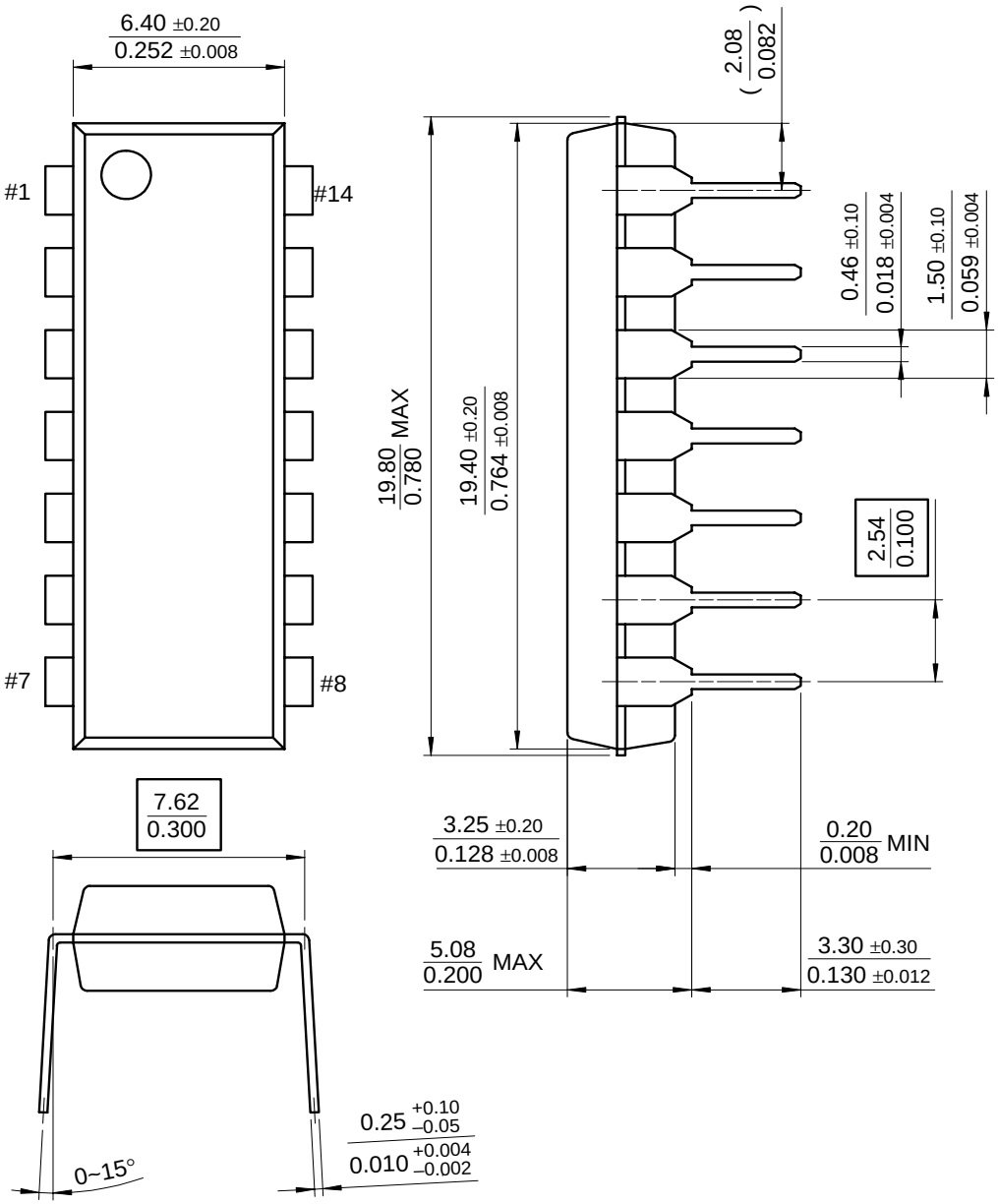
Figure 11. Current Limiting vs Temperature

Mechanical Dimensions

Package

Dimensions in millimeters

14-DIP

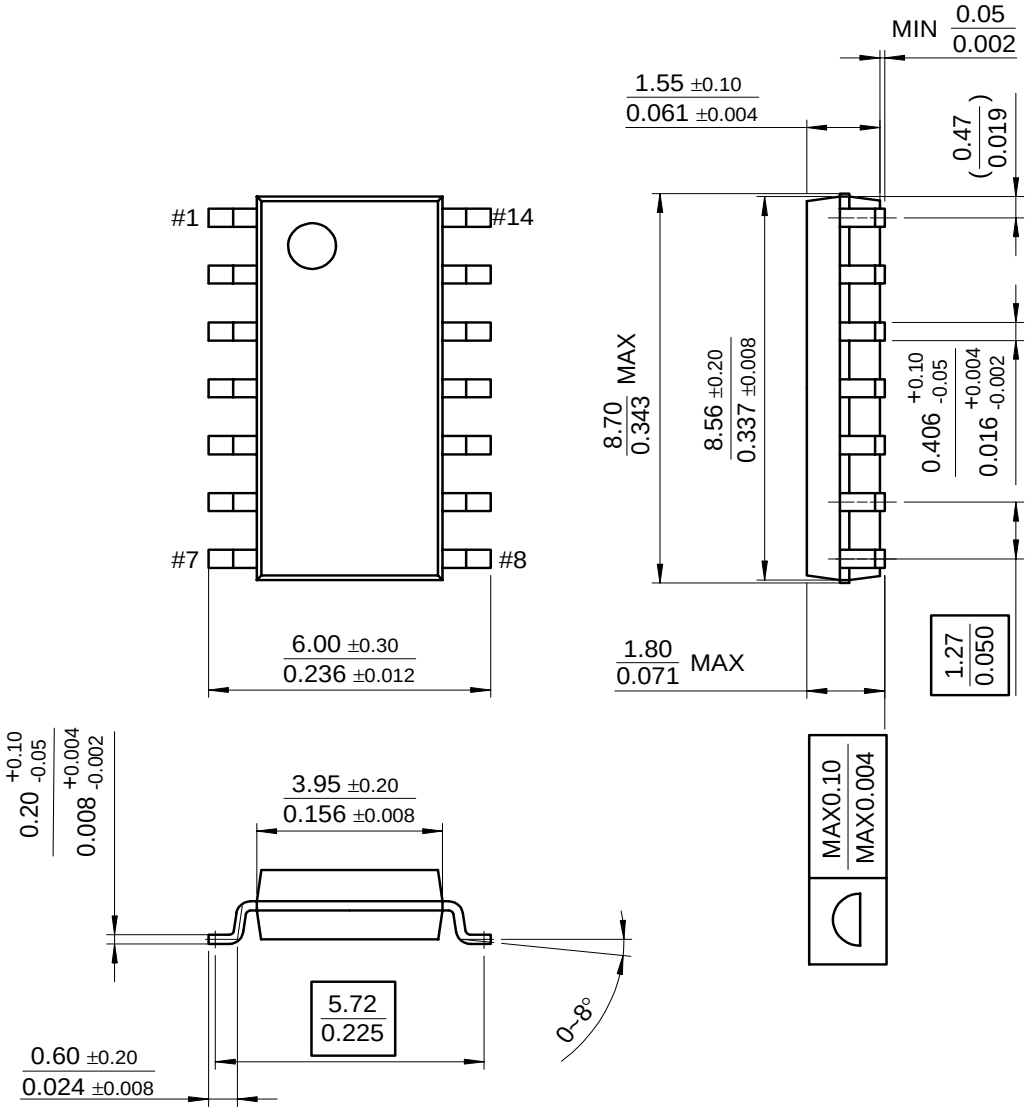


Mechanical Dimensions (Continued)

Package

Dimensions in millimeters

14-SOP



Ordering Information

Product Number	Package	Operating Temperature
LM324N	14-DIP	0 ~ +70°C
LM324AN		
LM324M	14-SOP	
LM324AM		
LM2902N	14-DIP	-40 ~ +85°C
LM2902M	14-SOP	
LM224N	14-DIP	-25 ~ +85°C
LM224AN		
LM224M	14-SOP	
LM224AM		

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